

MS2H40065G1

650V Silicon Carbide Diode

Features

- 650-Volt Schottky Rectifier
- Shorter recovery time
- High-speed switching possible
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on VF

Benefits

- Higher safety margin against overvoltage
- Improved efficiency all load conditions
- Increased efficiency compared to Silicon Diode alternatives
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway
- Essentially No Switching Losses

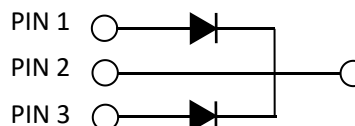
Applications

- Switch Mode Power Supplies
- Power Factor Correction
- Motor Drives
- HID Lighting

Package



Type : TO-247-3Lead



Absolute Maximum Ratings

 $T_c = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	MS2H40065G1	Units
VRRM	Repetitive Peak Reverse Voltage	650	V
VRSM	Surge Peak Reverse Voltage	650	V
VDC	DC Blocking Voltage	650	V
IF	Continuous Forward Current @Tc=150°C (Per Leg/Device)	20*/40	A
IFRM	Repetitive Peak Forward Surge Current (Per Leg) @TC=25°C, tP = 10 ms, Half Sine Wave	140	A
IFSM	Non-Repetitive Peak Forward Surge Current (Per Leg) @TC=25°C, tP = 10 ms, Half Sine Wave	170	A
IF,MAX	Non-Repetitive Peak Forward Surge Current @TC=25°C, tP = 10 us, Pulse	1360	A
Ptot	Power Dissipation @Tc=25°C @Tc=110°C	159 68	W
TJ, Tstg	Operating Junction and Storage Temperature	-55 to +175	°C

Electrical Characteristics

$T_C = 25^\circ \text{C}$ unless otherwise noted

Symbol	Test Conditions	Test Conditions	Min	Typ	Max	Unit
VF	Forward Voltage(Per Lag)	IF=20A, TC=25° C IF=20A, TC=175° C	-	1.45 1.85	1.8 2.4	V
IR	Reverse Current	VR=650V, TC=25° C VR=650V, TC=175° C	-	2 40	20 200	μA
QC	Total Capacitive Charge	VR =400V TJ = 25° C $Q_c = \int_0^{V_r} C(V) dv$	-	65	-	nC
C	Total Capacitance	VR =0V, TJ = 25° C, f=1MHz VR =200V, TJ = 25° C, f=1MHz VR =400V, TJ = 25° C, f=1MHz	-	1340 120 109	-	pF
EC	Capacitance Stored Energy	VR=400V	-	16	-	μJ

Thermal Characteristics

Symbol	Parameter	Typ	Unit
RθJC	Thermal Resistance from Junction to Case	0.94	°C/W

Typical Characteristics

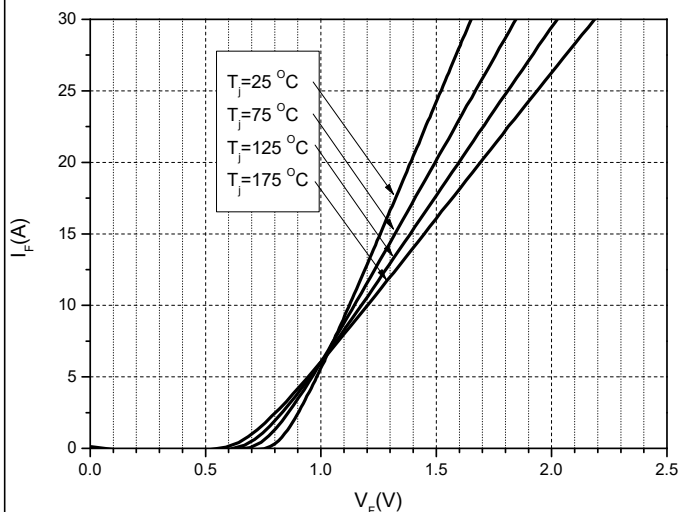


Figure 1. Forward Characteristics

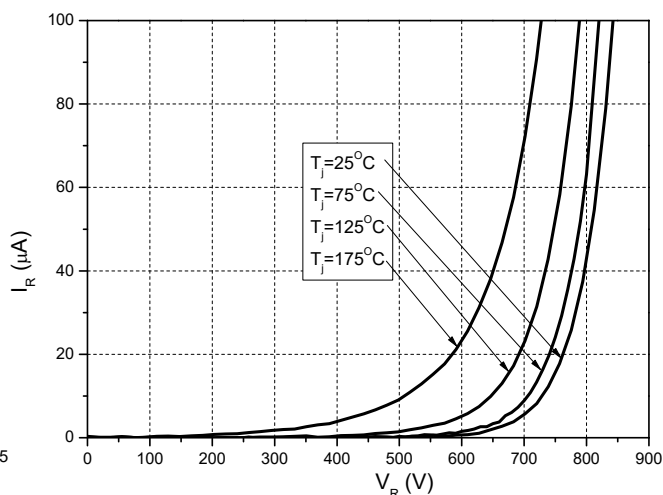


Figure 2. Reverse Characteristics

Typical Characteristics

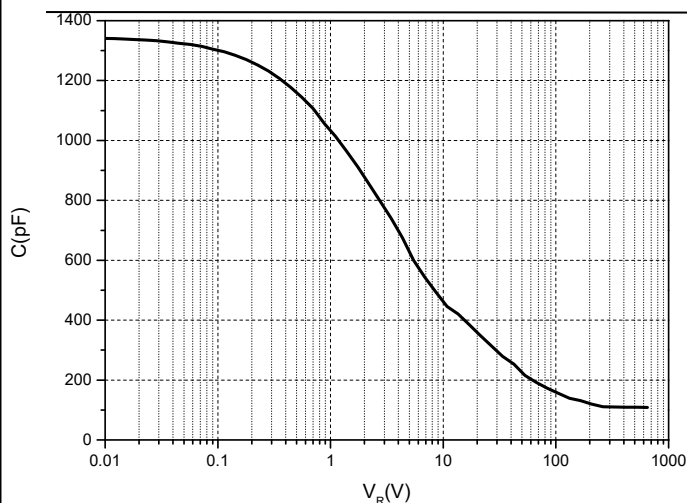


Figure 3. Capacitance vs. Reverse Voltage

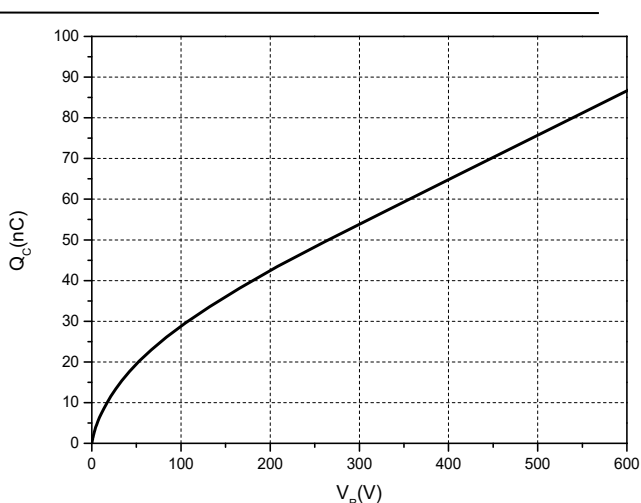


Figure 4. Total Capacitance Charge vs. Reverse Voltage

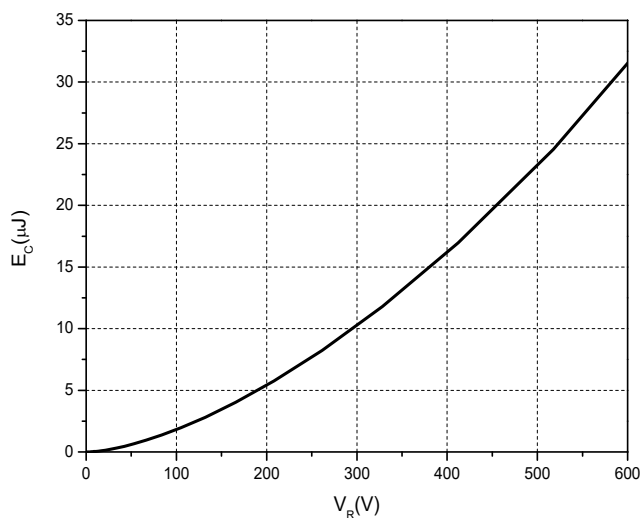


Figure 5. Capacitance Stored Energy

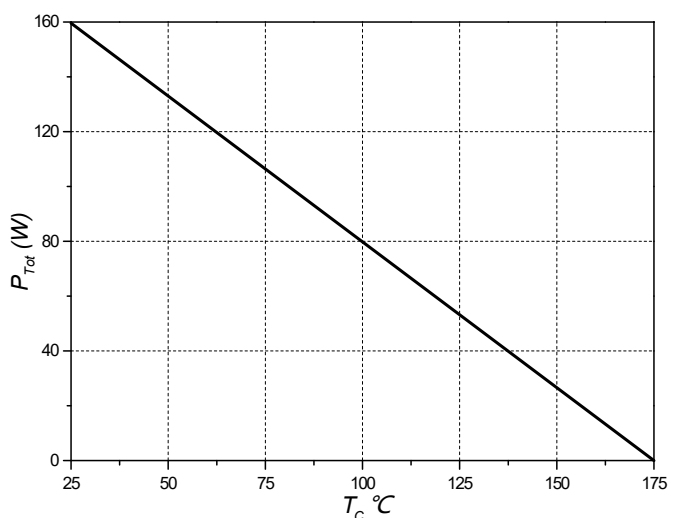


Figure 6. Power Derating

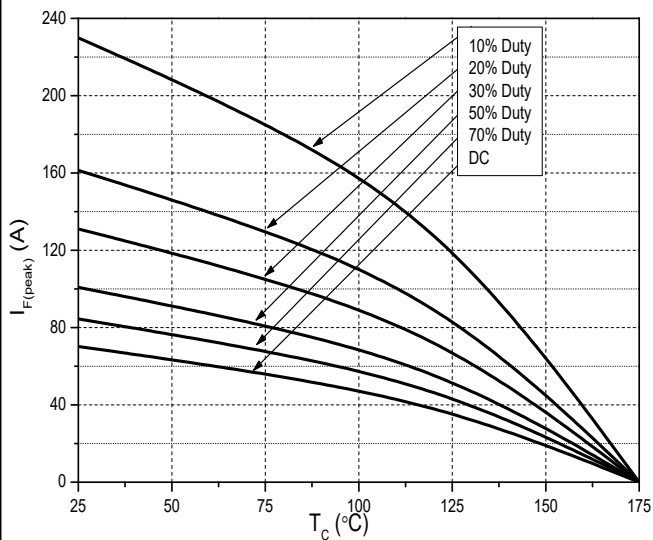


Figure 7. Current Derating

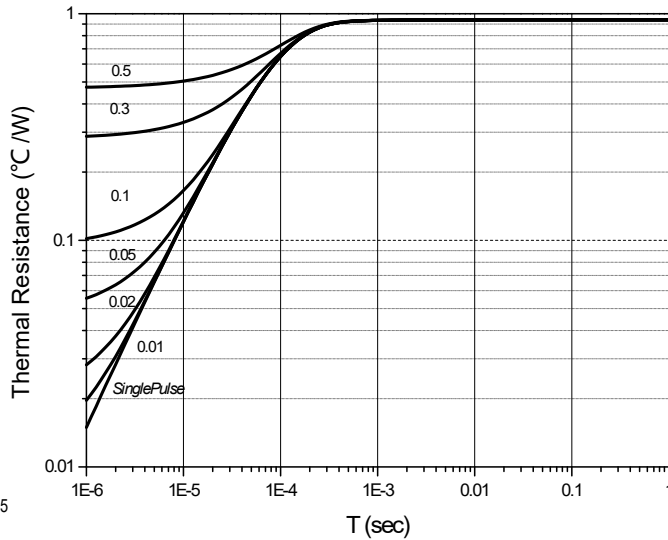
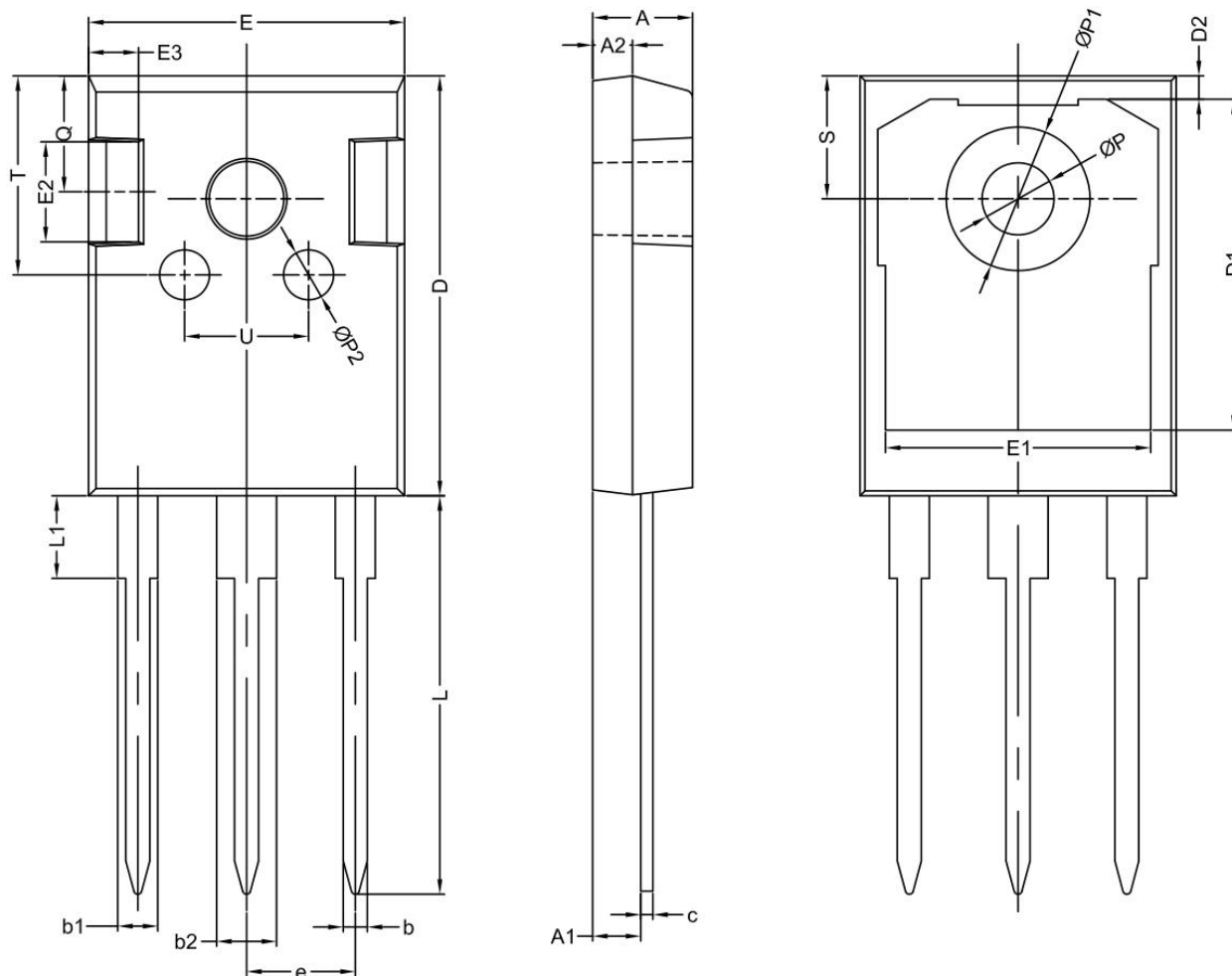


Figure 8. Transient Thermal Impedance

TO-247 OUTLINE



SYMBOL	Mechanical Dimensions/mm			SYMBOL	Mechanical Dimensions/mm			SYMBOL	Mechanical Dimensions/mm		
	MIN	NOM	MAX						MIN	NOM	MAX
A	4.80	5.00	5.20	D	20.80	21.00	21.20	L1	-	4.13	-
A1	2.21	2.41	2.61	D1	-	16.55	-	Ø P	3.5	3.6	3.7
A2	1.90	2.00	2.10	E	15.60	15.80	16.0	Ø P1	-	-	7.40
b	1.10	1.20	1.35	E1		13.3		Ø P2	-	2.50	-
b1	-	2.00	-	E2		5.0		Q	-	5.8	-
b2	-	3.00	-	e		5.44		S	6.05	6.15	6.25
c	0.55	0.60	0.75	L	19.42	19.92	20.42	T	-	10.0	-

NOTE:

- 1The plastic package is not marked as smooth surfaceRa=0.1;Subglossy surfaceRa=0.8
- 2.Undeclared tolerance ± 0.25 , Unmarked filletRmax=0.25

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